

DIGITALLY CONTROLLED HIGH AVAILABILITY POWER SUPPLY

David MacNair, Stanford Linear Accelerator Center, Menlo Park, CA

Abstract

This paper will report on the test results of a prototype 1320 watt power module for a high availability power supply. The module will allow parallel operation for N+1 redundancy with hot swap capability. The two quadrant output of each module allows pairs of modules to provide a 4 quadrant (bipolar) operation. Each module employs a novel 4 FET buck regulator arranged in a bridge configuration. Each side of the bridge alternately conducts through a small saturable ferrite that limits the reverse current in the FET body diode during turn off. This allows hard switching of the FETs with low switching losses. The module is designed with over-rated components to provide high reliability and better than 97% efficiency at full load. The modules use a Microchip DSP for control, monitoring, and fault detection. The switching FETs are driven by PWM modules in the DSP at 60 KHz. A Dual CAN bus interface provides for low cost redundant control paths. The DSP will also provide current sharing between modules, synchronized switching, and soft start up for hot swapping. The input and output of each module have low resistance FETs to allow hot swapping and isolation of faulted units.

Oversized components reduce conduction losses and improve efficiency. The digital control provides cycle by cycle voltage and current control to eliminate overloads in transient conditions.

ALTERNATING BUCK REGULATOR

An ideal topology would be a synchronous buck regulator. This provides the maximum power output for a given voltage rated FET. Replacing the free wheeling diode with a FET significantly reduces power loss. This also allows for 2 quadrant operation since the FET can conduct current in either direction. A pair of modules can provide bipolar output (four quadrant) when the load is connected between the two outputs. The non linear behavior at the transition of continuous diode conduction is eliminated, improving operation at low currents.

While synchronous regulators are common at low voltages and powers, the difficulty of synchronizing the switching of large devices has prevented their use at high power. If one device is turning on before the other turns off, massive currents will flow through both devices. In reverse conduction, if a device turns off prior to the other turning on, the current is forced into the intrinsic FET body diode. The typical high power FET diode has a slow recovery time, and a "snap off" recovery. Figure #2 shows the gate voltage and drain voltage of a IRFB3077 during turn off from a 30 amp reverse current. The extremely fast transition of the body diode causes the lead inductances to produce very large voltage transients inside the device.

OVERVIEW

This paper describes a module intended to be power DC magnets in a N+1 redundant configuration. The prototype is a 1320 watt (33A 40V) module, but the design can be easily scaled from 100 watts to 100 kW using the same digital control board. The reliability of the module is maximized by controlling all electrical and thermal stress.

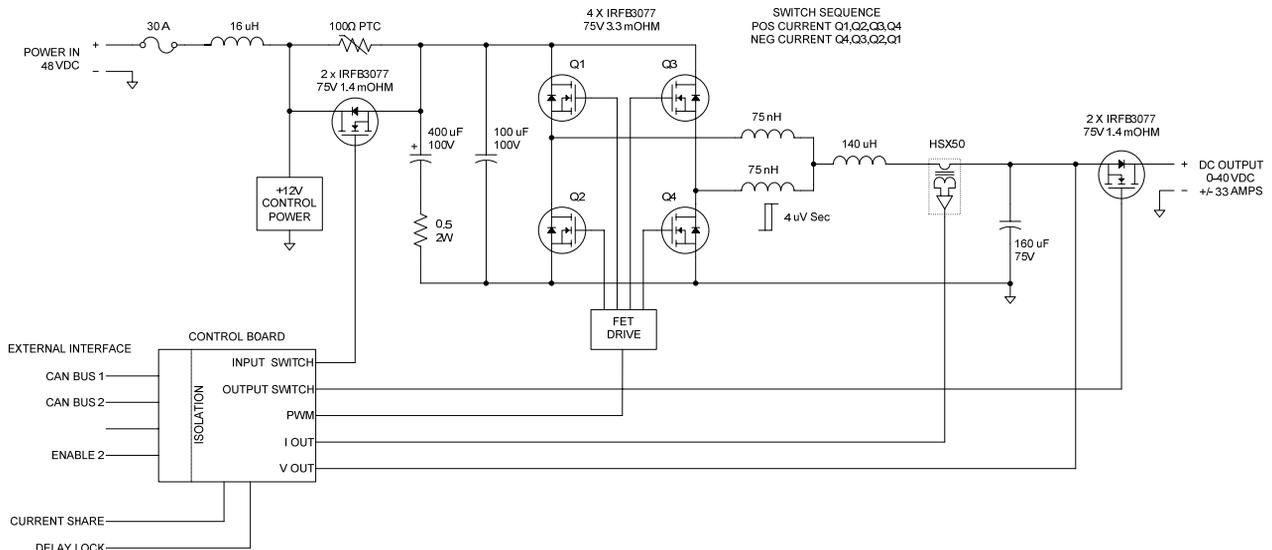


Figure 1. Two Quadrant DC-DC Converter with input and output FET switches

Work supported by the U.S. Department of Energy under contract number DE-AC02-76SF00515. SLAC-PUB-13589

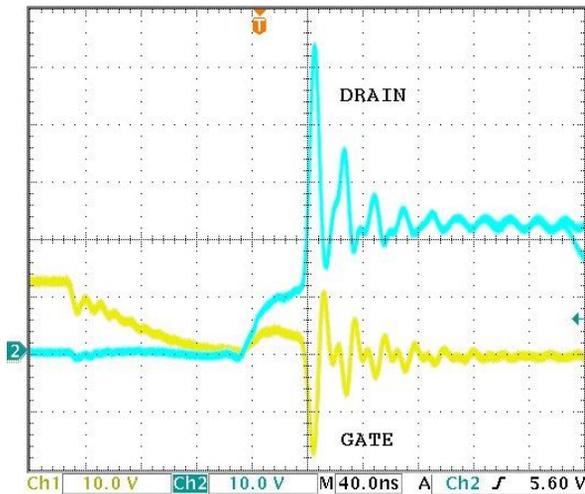


Figure 2: FET Diode Turn off 30 amps

A common approach is to increase the gate resistance of the FETs to slow down the switching speed, but at the cost of increased switching losses. The approach used for this module is to use a saturable inductor in series with the FET. The inductor un-saturates below 2 amps and provides a delay of 80 nSec before reversing direction. This allows time for the diode to fully recover. With the body diode recovery effects eliminated, the timing of the FET turn off is no longer critical. All FETs are turned off 100 nSec before any FET is turned on.

When a forward conducting FET turns off, the compliment FET on the same half bridge is turned on, leaving the current in the saturable inductors unchanged. When a reverse conducting FET turns off, the compliment FET on the other bridge turns on, forcing the current through the saturable inductors. This holds the current near zero to give the body diode time to recover before the drain voltage increases.

As shown in figure 1, the order the FETs are switched depends on the polarity of the output current. For a positive output current, Q2 and Q4 conduct in the reverse direction, so the sequence is Q1,Q2,Q3,Q4. For negative output current, Q1 and Q3 conduct in the reverse direction, so the sequence is reversed.

Because of the saturable inductors, the FETs turn on with zero current. The only loss is in the hysteresis of the ferrite cores. The ferrites used require around 4 uV-sec to completely reverse the field in the cores, resulting in an 80 nSec delay at 48 volts. The control board provides a 200 nSec minimum on time, which insures that the cores will always be completely reversed. Five TC6-4A11 cores were used with a single turn. The small core diameter provides a low saturation current for minimum core loss and maximizes cooling area.

The module must operate smoothly from zero to full voltage at any current. The topology allows for hard switching of the FETs with relatively small losses in the saturable ferrites and snubbers. Using oversized FETs with very low on resistance, and designing the magnetics for low resistance, allowed the module to exceed 98% efficiency at full load.

The module has FETs to modules with shorted components to be isolated from the input and output busses. The module uses two 3 milliohm FETs in parallel for each switch to reduce the conduction losses. The switch FET gates are driven by a photovoltaic devices to eliminate the need for isolated power. For a 10 mA input, they provide 9 volts to the gate. The turn on time is more than 1 millisecond, while a FET across the gate reduces the turn off to 100 microseconds.

CONTROL BOARD

The control board for the module uses a Microchip DSP (dsPIC60F12A) for control and communication. A serial 16 bit ADC is used to digitize the output voltage, and a serial 12 bit ADC digitizes the output current. The board is design to operate with switching frequencies of 20 to 100 kHz. For each switching cycle, the complete PID algorithm is run with the data from both ADCs. The DSP uses 4 of its 8 PWM outputs to control the FET gate drivers.

The magnet current will be regulated by an external redundant controllers. They will communicate the desired voltage to the module using the one of the redundant CAN bus interfaces. The modules use the CAN bus to transmit status information back to the current controller. The current regulator can update the desired voltage at up to 720 times per second. This will allow current regulation bandwidth of up to 100 Hz. The CAN bus address filters allows multicast and unicast messages. Multicast messages are used to set the voltage of all modules together, while unicast can enable or disable an individual module.

Figure 3 shows the PID (proportional, integral, derivative) algorithm used by the DSP. The voltage control includes two derivative terms (dV/dT and dI/dT) for increased flexibility. The current control also has a proportional term and two derivative terms. The integrator is shared by both to allow cycle by cycle switching between modes.

The module was tuned to a 1 KHz bandwidth for the voltage loop. The bandwidth was limited by the 1 KHz resonant frequency of the output filter. The step response of the voltage is shown in figure 3.

